

PC817 Series

※ Lead forming type (I type) and taping reel type (P type) are also available. (PC817/I/PC817/P)
 ※ TÜV (VDE0884) approved type is also available as an option.

■ Features

1. Current transfer ratio
 (CTR: MIN. 50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)

2. High isolation voltage between input and output ($V_{iso} : 5000\text{V}_{rms}$)

3. Compact dual-in-line package

PC817 : 1-channel type

PC827 : 2-channel type

PC837 : 3-channel type

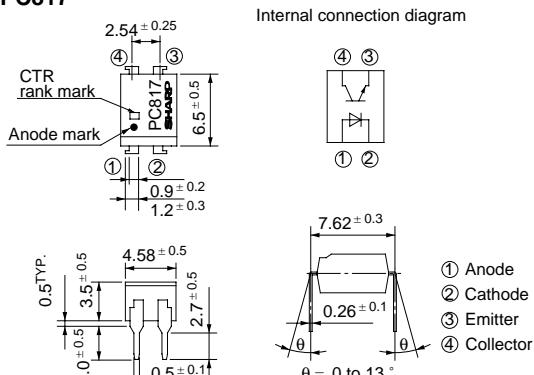
PC847 : 4-channel type

4. Recognized by UL, file No. E64380

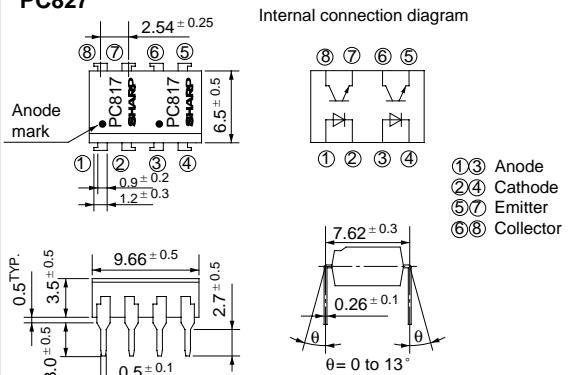
■ Outline Dimensions

(Unit: mm)

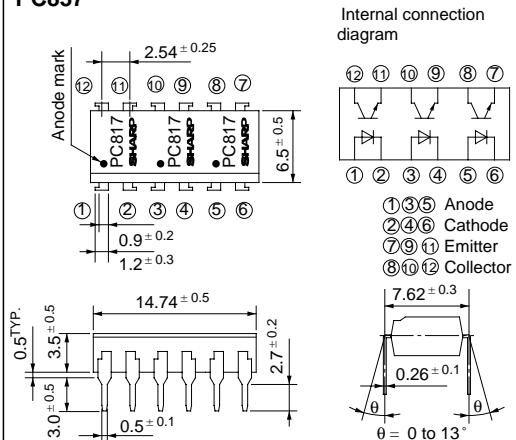
PC817



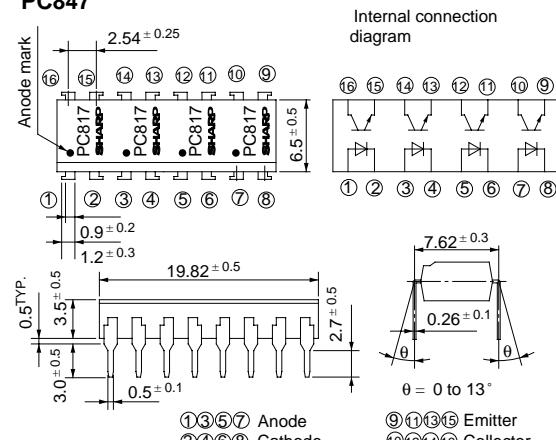
PC827



PC837



PC847



■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	* ¹ Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
Total power dissipation		P _{tot}	200	mW
* ² Isolation voltage		V _{iso}	5 000	V _{rms}
Operating temperature		T _{opr}	- 30 to +100	°C
Storage temperature		T _{stg}	- 55 to +125	°C
* ³ Soldering temperature		T _{sot}	260	°C

*1 Pulse width <=100μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

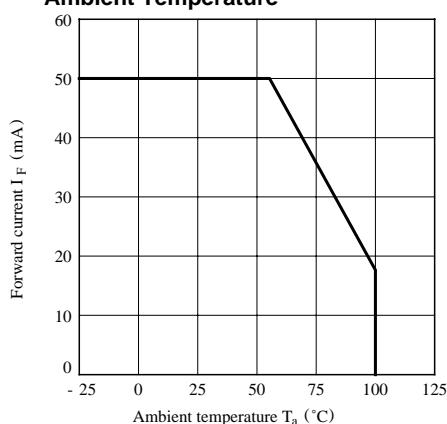
*3 For 10 seconds

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V	
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	-	-	3.0	V	
	Reverse current	I _R	V _R = 4V	-	-	10	μA	
	Terminal capacitance	C _t	V = 0, f = 1kHz	-	30	250	pF	
Output	Collector dark current	I _{CEO}	V _{CE} = 20V	-	-	10 ⁻⁷	A	
Transfer characteristics	* ⁴ Current transfer ratio	CTR	I _F = 5mA, V _{CE} = 5V	50	-	600	%	
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 1mA	-	0.1	0.2	V	
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω	
	Floating capacitance	C _f	V = 0, f = 1MHz	-	0.6	1.0	pF	
	Cut-off frequency	f _c	V _{CE} = 5V, I _C = 2mA, R _L = 100Ω, -3dB	-	80	-	kHz	
	Response time	Rise time	t _r	V _{CE} = 2V, I _C = 2mA, R _L = 100Ω	-	4	18	μs
		Fall time	t _f		-	3	18	μs

*4 Classification table of current transfer ratio is shown below.

Fig. 1 Forward Current vs. Ambient Temperature

* : 1 or 2 or 3 or 4

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	B	130 to 260
PC817C	C	200 to 400
PC817D	D	300 to 600
PC817AB	A or B	80 to 260
PC817BC	B or C	130 to 400
PC817CD	C or D	200 to 600
PC817AC	A, B or C	80 to 400
PC817BD	B, C or D	130 to 600
PC817AD	A, B, C or D	80 to 600
PC817	A, B, C, D or No mark	50 to 600

Fig. 2 Collector Power Dissipation vs. Ambient Temperature

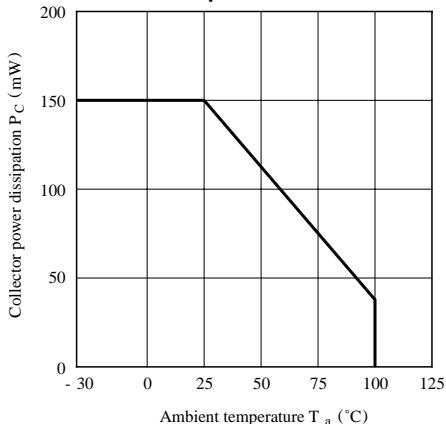


Fig. 4 Current Transfer Ratio vs. Forward Current

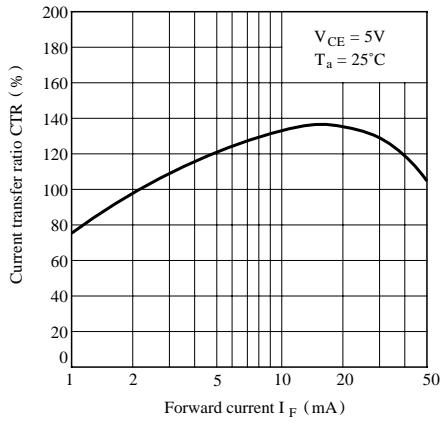


Fig. 6 Collector Current vs. Collector-emitter Voltage

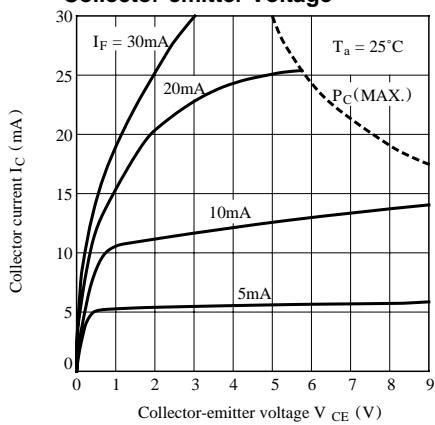


Fig. 3 Peak Forward Current vs. Duty Ratio

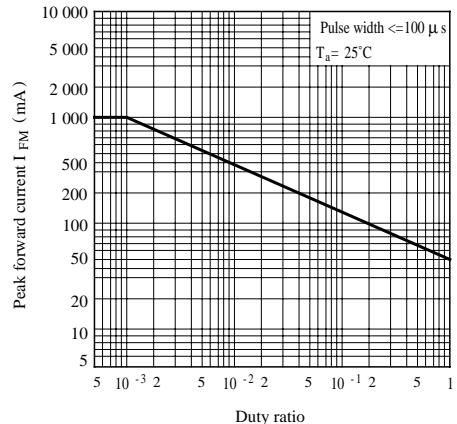


Fig. 5 Forward Current vs. Forward Voltage

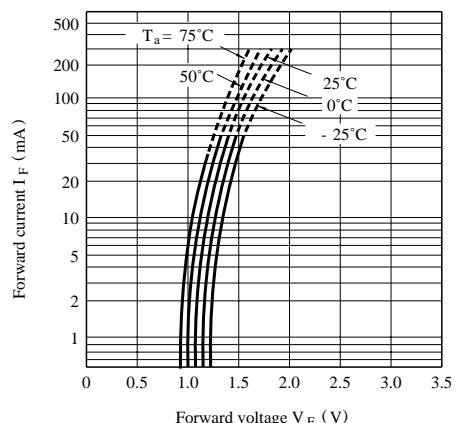


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

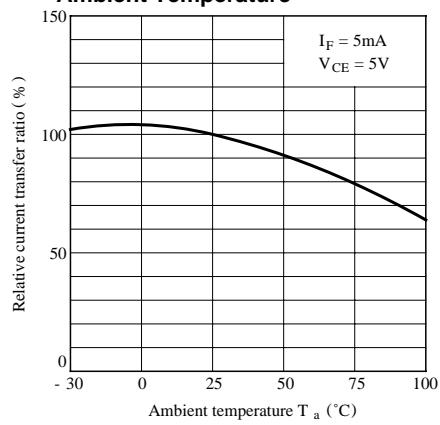


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

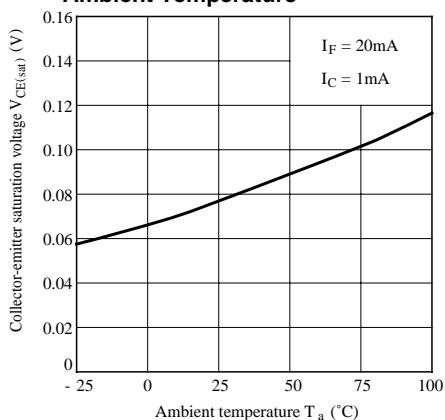


Fig. 9 Collector Dark Current vs. Ambient Temperature

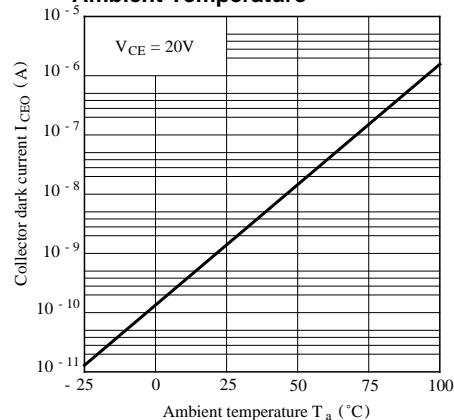


Fig.10 Response Time vs. Load Resistance

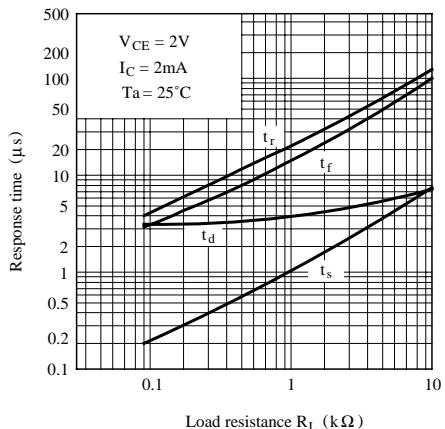


Fig.11 Frequency Response

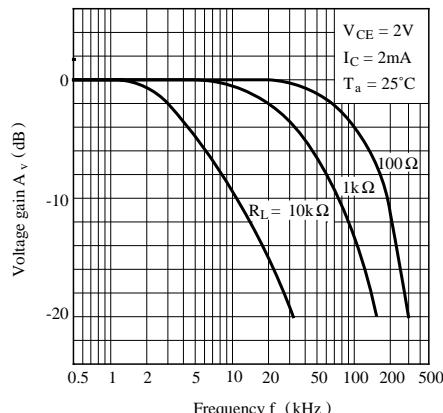
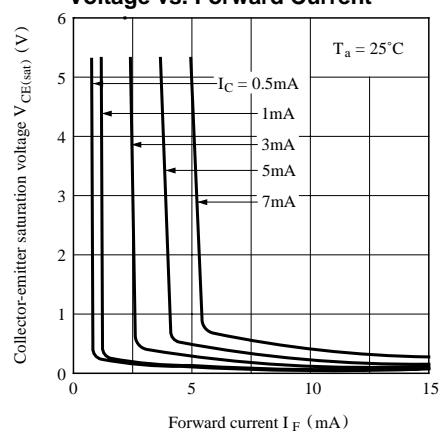
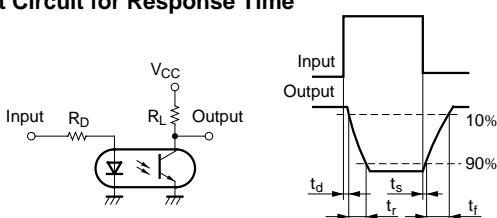


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Response Time



Test Circuit for Frequency Response

